RT1N44HX SERIES

(Transistor)

Transistor With Resistor
For Switching Application

Silicon NPN Epitaxial Type

DESCRIPTION

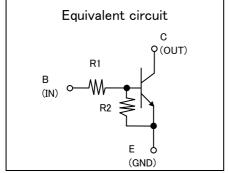
RT1N44HX is one chip transistor with built-in bias resistor, PNP type is RT1P44HX.

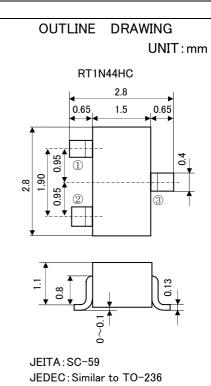
FEATURE

•Built-in bias resistor (R1=47k Ω ,R2=22k Ω).

APPLICATION

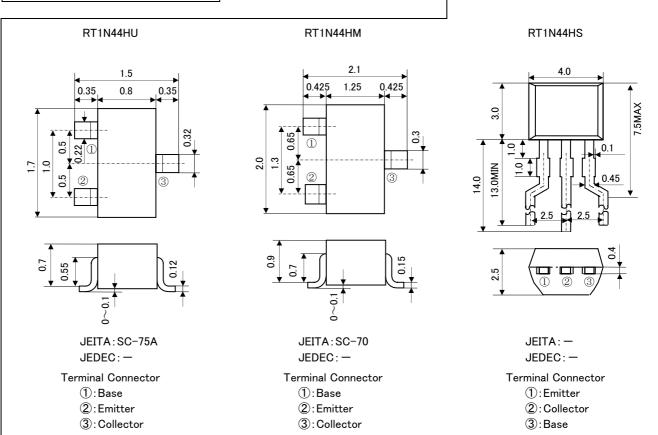
Inverted circuit, switching circuit, interface circuit, driver circuit.





Terminal Connector

①:Base
②:Emitter
③:Collector

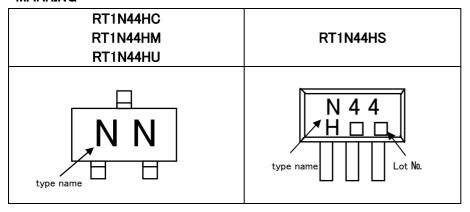


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MARKING



MAXIMUM RATING (Ta=25°C)

| SYMBOL | PARAMETER | RATING | | | | |
|------------------|--------------------------------|-------------------|----------|----------|----------|------|
| | | RT1N44HU | RT1N44HM | RT1N44HC | RT1N44HS | UNIT |
| V _{CBO} | Collector to Base voltage | 50 | | | | |
| V _{EBO} | Emitter to Base voltage | 10 | | | | |
| V _{CEO} | Collector to Emitter voltage | 50 | | | | |
| V_{IN} | Input voltage | 40 | | | | |
| Ι _C | Collector current | 100 | | | | |
| I _{CM} | Peak Collector current | 200 | | | | |
| P _c | Collector dissipation(Ta=25°C) | 150 | 20 | 00 | 450 | mW |
| Tj | Junction temperature | +150 | | | | °C |
| Tstg | Storage temperature | −55 ~ +150 | | | | °C |

ELECTRICAL CHARACTERISTICS (Ta=25°C)

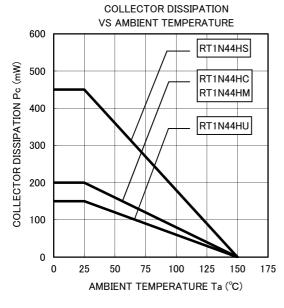
| SYMBOL | PARAMETER | TEST CONDITION | LIMIT | | | UNIT |
|---------------------------|---------------------------|---|-------|------|------|------|
| STWIDOL | | TEST CONDITION | MIN | TYP | MAX | UNIT |
| $V_{(BR)CEO}$ | C to E break down voltage | I _C =100 μ A, R _{BE} =∞ | 50 | _ | 1 | V |
| I _{CBO} | Collector cut off current | V_{CB} =50V, I $_{E}$ =0 | l | _ | 0.1 | μΑ |
| I _{EBO} | Emitter cut off current | V_{EB} =5V, I $_{C}$ =0 | 54 | 72 | 105 | μΑ |
| h _{FE} | DC forward current gain | V_{CE} =5V, I $_{C}$ =5mA | 56 | _ | 1 | _ |
| $V_{CE(sat)}$ | C to E saturation voltage | I_{C} =10mA, I_{B} =0.5mA | ı | _ | 0.3 | V |
| $V_{I(ON)}$ | Input on voltage | V_{CE} =0.2V, I $_{C}$ =5mA | 1 | 2.6 | 6.3 | V |
| $V_{I(OFF)}$ | Input off voltage | V_{CE} =5V, I $_{C}$ =100 μ A | 1.3 | 1.7 | ı | V |
| R ₁ | Input resistor | _ | 33 | 47 | 61 | kΩ |
| R_2/R_1 | Resistor ratio | _ | 0.37 | 0.47 | 0.57 | _ |
| f_{\scriptscriptstyleT} | Gain band width product | V_{CE} =6V, I_{E} =-10mA | - | 200 | _ | MHz |

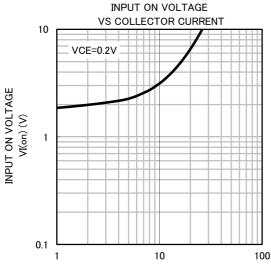
〈Transistor〉

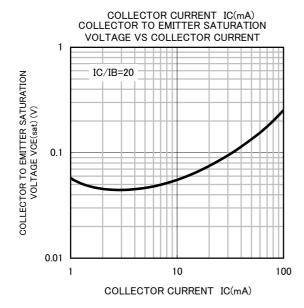
RT1N44HX SERIES

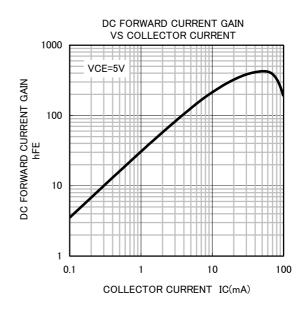
Transistor With Resistor For Switching Application Silicon NPN Epitaxial Type

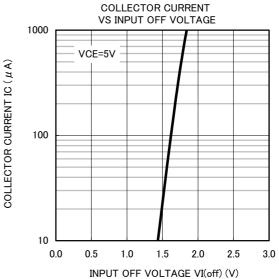
TYPICAL CHARACTERISTICS (Ta=25°C)













Keep safety first in your circuit designs!

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